

# Standard Rectifier Module

$$V_{RRM} = 1200\text{ V}$$

$$I_{FAV} = 560\text{ A}$$

$$V_F = 0,98\text{ V}$$

## Single Diode

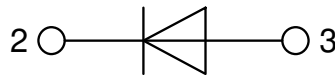
Part number

**MDO500-12N1**



Backside: isolated

 E72873



### Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

### Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

### Package: Y1

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Base plate: Copper internally DCB isolated
- Advanced power cycling

### Disclaimer Notice

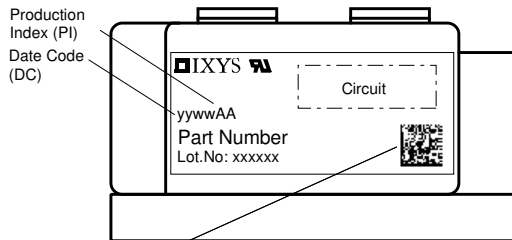
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| Rectifier    |                                              |                                        |         | Ratings                      |       |       |                   |
|--------------|----------------------------------------------|----------------------------------------|---------|------------------------------|-------|-------|-------------------|
| Symbol       | Definition                                   | Conditions                             |         | min.                         | typ.  | max.  | Unit              |
| $V_{RSM}$    | max. non-repetitive reverse blocking voltage |                                        |         |                              |       | 1300  | V                 |
| $V_{RRM}$    | max. repetitive reverse blocking voltage     |                                        |         |                              |       | 1200  | V                 |
| $I_R$        | reverse current                              | $V_R = 1200\text{ V}$                  |         | $T_{VJ} = 25^\circ\text{C}$  |       | 1     | mA                |
|              |                                              | $V_R = 1200\text{ V}$                  |         | $T_{VJ} = 140^\circ\text{C}$ |       | 30    | mA                |
| $V_F$        | forward voltage drop                         | $I_F = 500\text{ A}$                   |         | $T_{VJ} = 25^\circ\text{C}$  |       | 1,09  | V                 |
|              |                                              | $I_F = 1000\text{ A}$                  |         |                              |       | 1,24  | V                 |
|              |                                              | $I_F = 500\text{ A}$                   |         | $T_{VJ} = 125^\circ\text{C}$ |       | 0,98  | V                 |
|              |                                              | $I_F = 1000\text{ A}$                  |         |                              |       | 1,17  | V                 |
| $I_{FAV}$    | average forward current                      | $T_C = 85^\circ\text{C}$               |         | $T_{VJ} = 140^\circ\text{C}$ |       | 560   | A                 |
| $I_{F(RMS)}$ | RMS forward current                          | 180° sine                              | d = 0.5 |                              |       |       | A                 |
| $V_{F0}$     | threshold voltage                            |                                        |         | $T_{VJ} = 140^\circ\text{C}$ |       | 0,80  | V                 |
| $r_F$        | slope resistance                             |                                        |         |                              |       | 0,38  | mΩ                |
| $R_{thJC}$   | thermal resistance junction to case          |                                        |         |                              |       | 0,072 | K/W               |
| $R_{thCH}$   | thermal resistance case to heatsink          |                                        |         |                              | 0,024 |       | K/W               |
| $P_{tot}$    | total power dissipation                      |                                        |         | $T_C = 25^\circ\text{C}$     |       | 1600  | W                 |
| $I_{FSM}$    | max. forward surge current                   | t = 10 ms; (50 Hz), sine               |         | $T_{VJ} = 45^\circ\text{C}$  |       | 15,0  | kA                |
|              |                                              | t = 8,3 ms; (60 Hz), sine              |         | $V_R = 0\text{ V}$           |       | 16,2  | kA                |
|              |                                              | t = 10 ms; (50 Hz), sine               |         | $T_{VJ} = 140^\circ\text{C}$ |       | 12,8  | kA                |
|              |                                              | t = 8,3 ms; (60 Hz), sine              |         | $V_R = 0\text{ V}$           |       | 13,8  | kA                |
| $I^2t$       | value for fusing                             | t = 10 ms; (50 Hz), sine               |         | $T_{VJ} = 45^\circ\text{C}$  |       | 1,13  | MA <sup>2</sup> s |
|              |                                              | t = 8,3 ms; (60 Hz), sine              |         | $V_R = 0\text{ V}$           |       | 1,09  | MA <sup>2</sup> s |
|              |                                              | t = 10 ms; (50 Hz), sine               |         | $T_{VJ} = 140^\circ\text{C}$ |       | 812,8 | kA <sup>2</sup> s |
|              |                                              | t = 8,3 ms; (60 Hz), sine              |         | $V_R = 0\text{ V}$           |       | 788,8 | kA <sup>2</sup> s |
| $C_J$        | junction capacitance                         | $V_R = 400\text{ V}; f = 1\text{ MHz}$ |         | $T_{VJ} = 25^\circ\text{C}$  |       | 762   | pF                |



| Package Y1    |                                                              |                      | Ratings |      |      |      |
|---------------|--------------------------------------------------------------|----------------------|---------|------|------|------|
| Symbol        | Definition                                                   | Conditions           | min.    | typ. | max. | Unit |
| $I_{RMS}$     | RMS current                                                  | per terminal         |         |      | 600  | A    |
| $T_{VJ}$      | virtual junction temperature                                 |                      | -40     |      | 140  | °C   |
| $T_{op}$      | operation temperature                                        |                      | -40     |      | 125  | °C   |
| $T_{stg}$     | storage temperature                                          |                      | -40     |      | 125  | °C   |
| <b>Weight</b> |                                                              |                      |         | 650  |      | g    |
| $M_D$         | mounting torque                                              |                      | 4,5     |      | 7    | Nm   |
| $M_T$         | terminal torque                                              |                      | 11      |      | 13   | Nm   |
| $d_{Spp/App}$ | creepage distance on surface   striking distance through air | terminal to terminal | 16,0    |      |      | mm   |
| $d_{Spb/Apb}$ |                                                              | terminal to backside | 25,0    |      |      | mm   |
| $V_{ISOL}$    | isolation voltage                                            | t = 1 second         | 4800    |      |      | V    |
|               |                                                              | t = 1 minute         | 4000    |      |      | V    |



Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.# (33-36)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | MDO500-12N1     | MDO500-12N1        | Box           | 2        | 464791   |

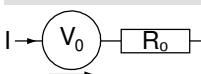
| Similar Part | Package | Voltage class |
|--------------|---------|---------------|
| MDO500-14N1  | Y1-2-CU | 1400          |
| MDO500-16N1  | Y1-2-CU | 1600          |
| MDO500-18N1  | Y1-2-CU | 1800          |
| MDO500-20N1  | Y1-2-CU | 2000          |

|             |         |      |
|-------------|---------|------|
| MDO500-22N1 | Y1-2-CU | 2200 |
|-------------|---------|------|

**Equivalent Circuits for Simulation**

\* on die level

$T_{VJ} = 140^{\circ}C$

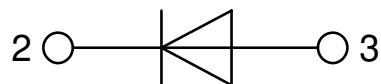
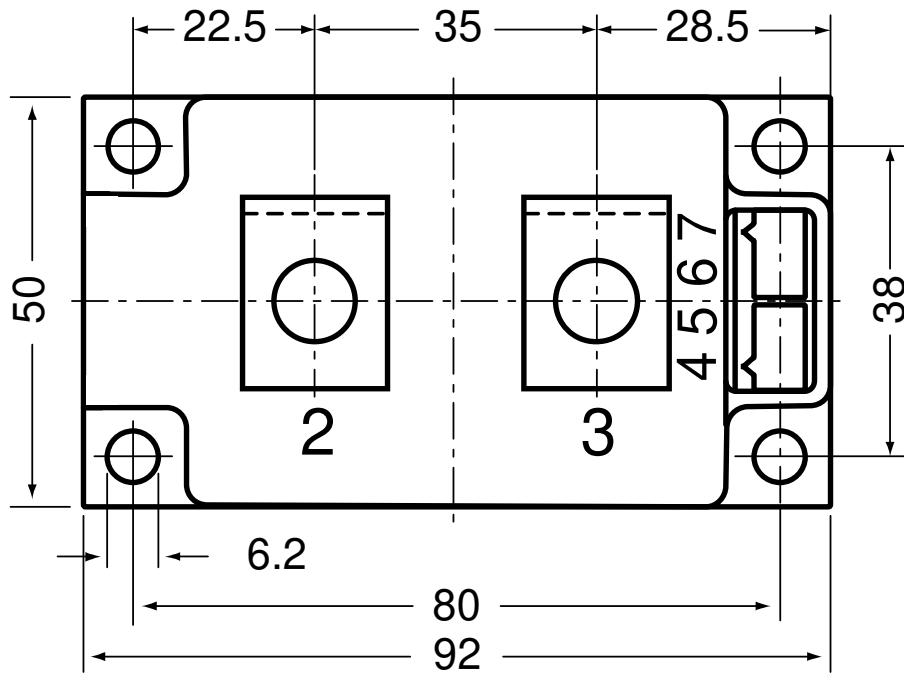
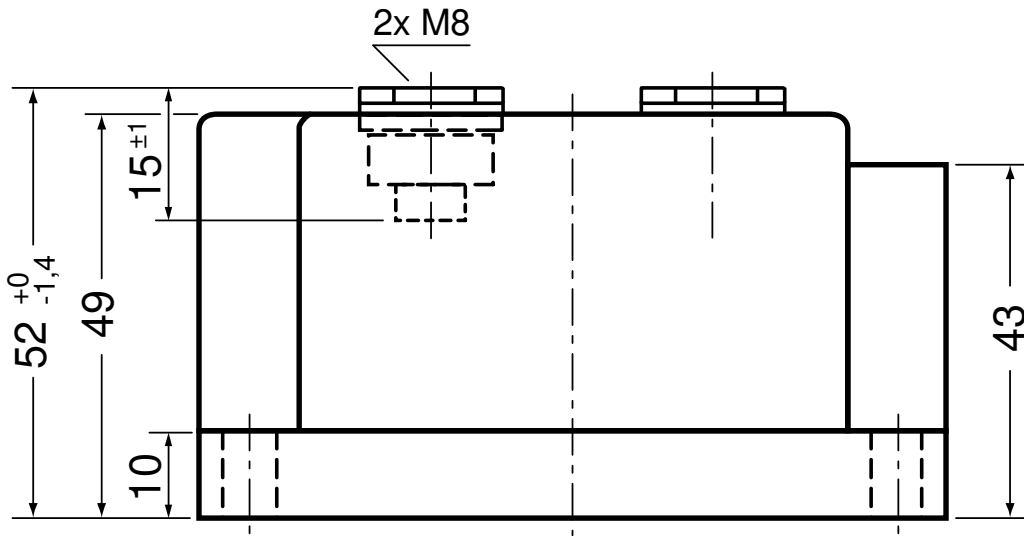


Rectifier

|              |                    |      |    |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage  | 0,8  | V  |
| $R_{0\ max}$ | slope resistance * | 0,19 | mΩ |



Outlines Y1





**Rectifier**



Fig. 1 Surge overload current  
 $I_{FSM}$ : Crest value,  $t$ : duration



Fig. 2  $I^2t$  versus time (1-10 ms)

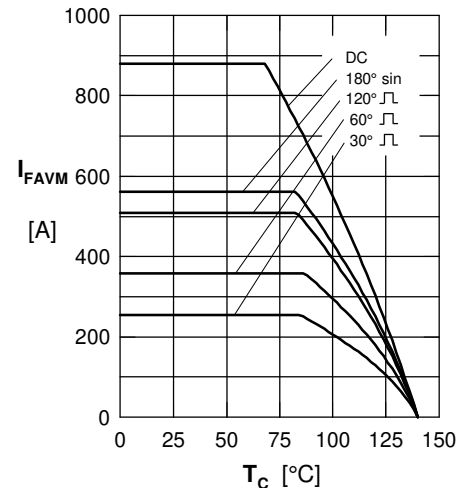


Fig. 3 Maximum forward current at case temperature

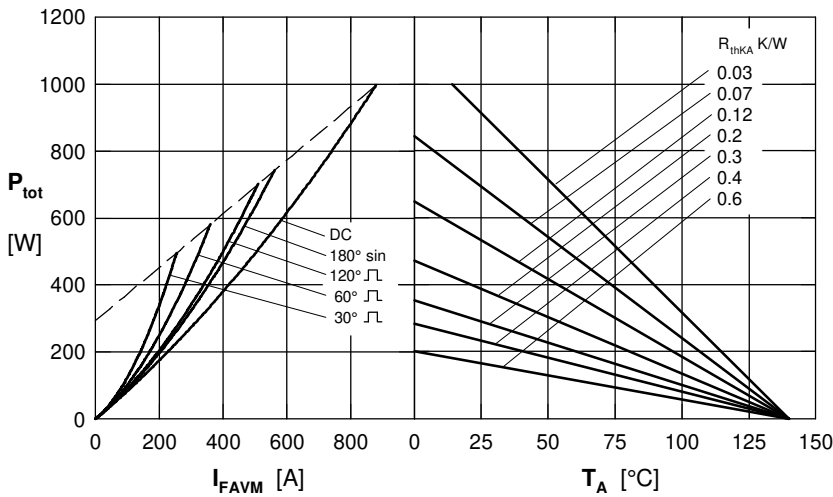


Fig. 4 Power dissipation vs. forward current and ambient temperature

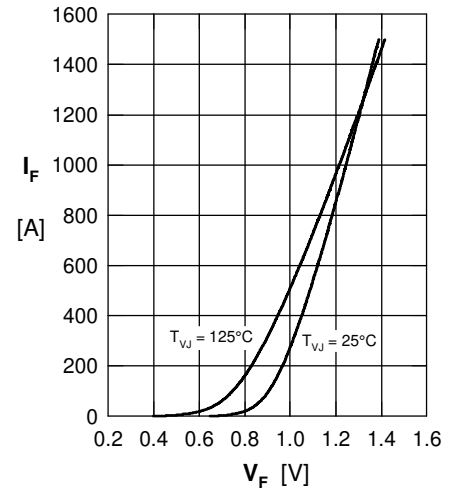


Fig. 5 Forward current  $I_F$  versus  $V_F$

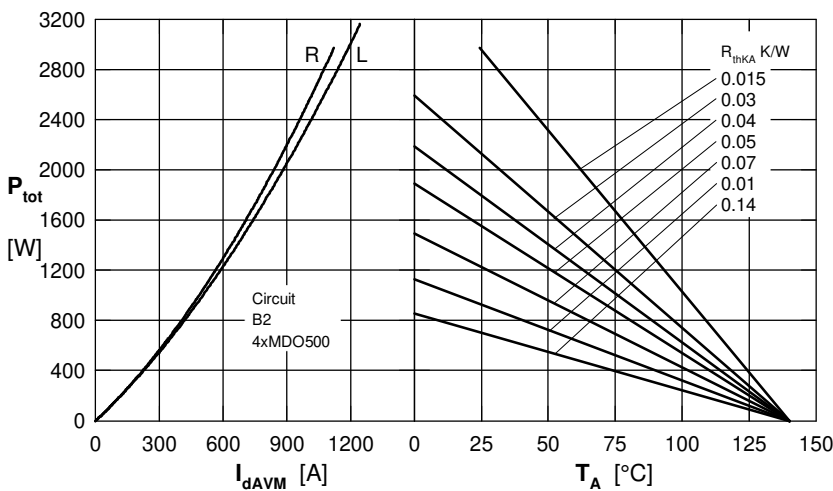


Fig. 6 Single phase rectifier bridge: Power dissipation vs. direct output current and ambient temperature. R = resistive load, L = inductive load

**Rectifier**

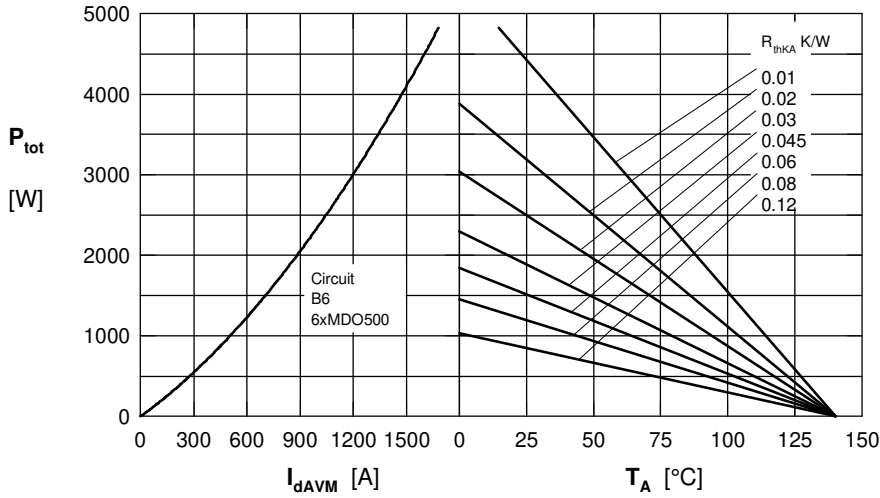
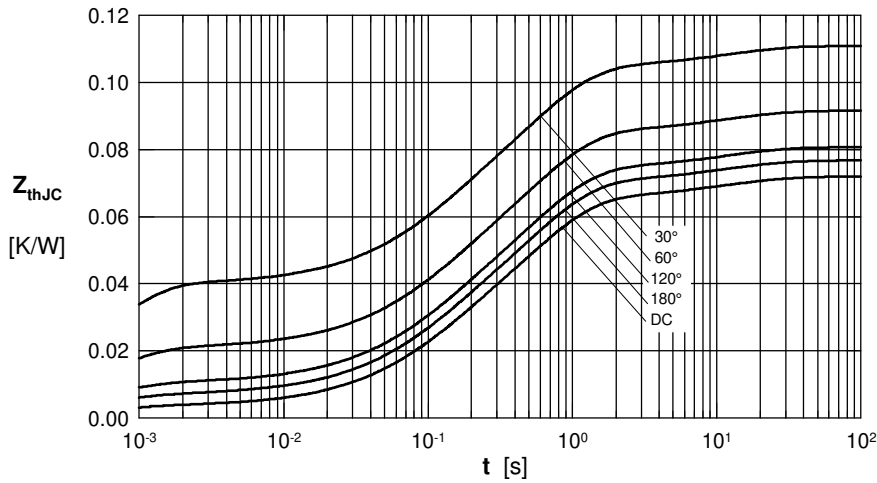


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature



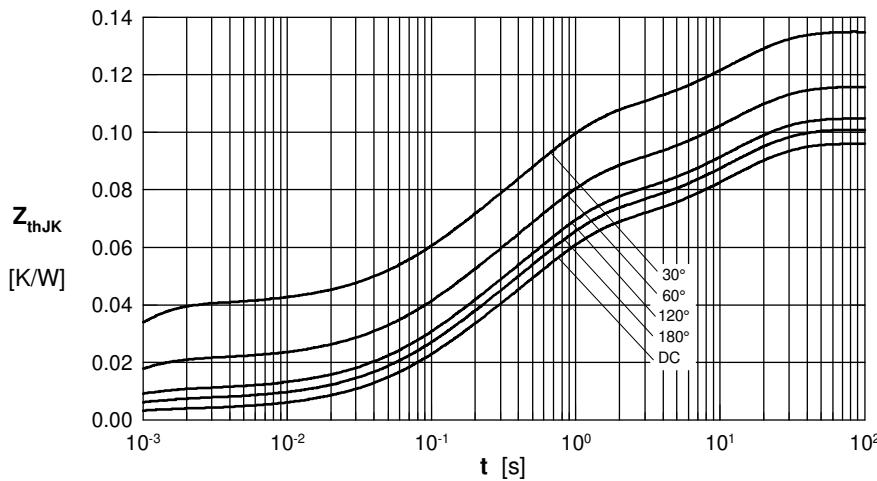
$R_{thJC}$  for various conduction angles d:

| d    | $R_{thJC}$ (K/W) |
|------|------------------|
| DC   | 0.072            |
| 180° | 0.0768           |
| 120° | 0.081            |
| 60°  | 0.092            |
| 30°  | 0.111            |

Constants for  $Z_{thJC}$  calculation:

| i | $R_{thi}$ (K/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 0.0035          | 0.0054    |
| 2 | 0.0186          | 0.098     |
| 3 | 0.0432          | 0.54      |
| 4 | 0.0067          | 12        |

Fig. 7 Transient thermal impedance junction to case



$R_{thJK}$  for various conduction angles d:

| d    | $R_{thJK}$ (K/W) |
|------|------------------|
| DC   | 0.096            |
| 180° | 0.1              |
| 120° | 0.105            |
| 60°  | 0.116            |
| 30°  | 0.135            |

Constants for  $Z_{thJK}$  calculation:

| i | $R_{thi}$ (K/W) | $t_i$ (s) |
|---|-----------------|-----------|
| 1 | 0.0035          | 0.0054    |
| 2 | 0.0186          | 0.098     |
| 3 | 0.0432          | 0.54      |
| 4 | 0.0067          | 12        |
| 5 | 0.024           | 12        |

Fig. 8 Transient thermal impedance junction to heatsink